NSN 5961-01-060-4951

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-060-4951 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.540 inches **End Application:** Next generation radar (nexrad) **Mounting Method:** Compression **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2400.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 470.00 amperes collector current, dc of standard range **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No Fiig: A110a0